

High-Power 10 W 9xx nm Fiber-Coupled Diode Laser with Feedback Protection

6398-L4*i* Series



Key Features

- Full fiber laser feedback protection
- 10 W output power
- · High reliability
- 105 µm aperture
- 0.22 or 0.15 N A
- Isolated electrical contacts

Application

• Fiber laser pumping

The JDSU L4i Series fiber-coupled diode laser is the latest solution in our L4 platform for the fiber laser pumping market.

The L4*i* design, which leverages the L4 footprint, offers a high degree of feedback protection from any fiber laser wavelength. This feature allows end users to operate the fiber laser in an environment virtually free from the risk of feedback to the diode laser, resulting in a less costly solution than a traditional isolation system.

Our 6398-L4i series diode lasers offer 10 W of power from a 105 μ m fiber. In addition, the L4i multimode pump modules take advantage of the existing global JDSU manufacturing infrastructure to offer both high brightness and a small footprint, with consistent high reliability in a cost-effective solution.

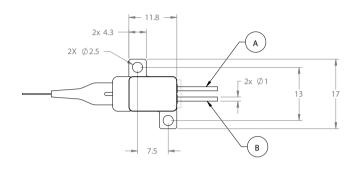
Dimensions Diagram

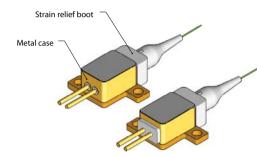
(Specifications in mm unless otherwise noted.)

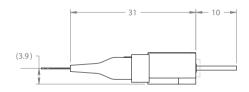
Standard Tolerances

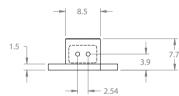
mm: $x.x = \pm 0.5$

 $x.xx = \pm 0.25$









Pinout

Pin	Description	
A	Laser cathode (-)	
В	Laser anode (+)	

Specifications for 0.22NA¹

Parameter	Symbol	Minimum	Typical	Maximum
Laser Characteristics				
CW output power	Po	-	-	10 W
Mean wavelength ²	λ _{p 915 nm}	905 nm	917 nm	928 nm
	λp 940 nm	928 nm	939 nm	950 nm
	λ_p 975 nm	963 nm	974 nm	985 nm
Spectral width (FWHM)	Δλ	-	3 nm	6 nm
Slope efficiency	$\eta_{\mathrm{D}915\mathrm{nm}}$	-	0.93 W/A	-
	$\eta_{\mathrm{D}940\mathrm{nm}}$	-	0.92 W/A	-
	$\eta_{\mathrm{D}975\;\mathrm{nm}}$	-	0.90 W/A	-
Conversion efficiency	η	-	48%	-
Threshold current	Ith	-	600 mA	850 mA
Operating current	Iop 915 nm	-	11.4 A	12.5 A
	$ m I_{op}$ 940 nm	-	11.7 A	12.8 A
	Iop 975 nm	-	11.8 A	13.0 A
Forward voltage	Vf	-	1.81 V	2.0 V
Series resistance	Rs	-	$0.04~\Omega$	-
Recommended case temperature	Tc	20 °C	25 °C	40 °C
Wavelength tuning vs. temperature ³	Δλ/ΔΤ	-	0.35 nm/°C	-
Wavelength tuning vs. output power	Δλ/ΔΡ	-	1.0 nm/W	-
Fiber Characteristics				
Fiber core diameter	dc	-	105 μm	-
Fiber numerical aperture	NA	0.20	0.22	0.24
Fiber cladding	dcl	-	125 μm	-
Fiber buffer	dь	-	250 μm	-
Fiber length	lf	0.9 m	1 m	-

^{1.} All performance data measured at 10 W, 25 °C, beginning of Life (BOL). 2. Weighted average "center of mass" spectral point at 25 °C at $P_{\rm O}$ 3. Change in $\Delta\lambda$ mean with case temperature over $T_{\rm op}$

Specification for 0.15 NA¹

Parameter	Symbol	Minimum	Typical	Maximum
Laser Characteristics				
CW output power	Po	-	-	10 W
Mean wavelength ²	λp 915 nm	905 nm	917 nm	928 nm
	λp 940 nm	928 nm	939 nm	950 nm
	λ_p 975 nm	963 nm	974 nm	985 nm
Spectral width (FWHM)	Δλ	-	3 nm	6 nm
Slope efficiency	$\eta_{\mathrm{D}915\mathrm{nm}}$	-	0.91 W/A	-
	$\eta_{\rm D940nm}$	-	0.90 W/A	-
	$\eta_{\mathrm{D}975\;\mathrm{nm}}$	-	0.90 W/A	-
Conversion efficiency	η	-	46%	-
Threshold current	Ith	-	600 mA	850 mA
Operating current	Iop 915 nm	-	12.0 A	13.0 A
	$ m I_{op}$ 940 nm	-	12.2 A	13.5 A
	Iop 975 nm	-	12.3 A	13.5 A
Forward voltage	Vf	-	1.82 V	2.0 V
Series resistance	Rs	-	$0.04~\Omega$	-
Recommended case temperature	Tc	20 °C	25 °C	40 °C
Wavelength tuning vs. temperature ³	Δλ/ΔΤ	-	0.35 nm/°C	-
Wavelength tuning vs. output power	Δλ/ΔΡ	-	1.0 nm/W	-
Fiber Characteristics				
Fiber core diameter	dc	-	105 μm	-
Fiber numerical aperture	NA	0.135	0.15	0.165
Fiber cladding	dd	-	125 μm	-
Fiber buffer	dь	-	250 μm	-
Fiber length	lf	0.9 m	1 m	-

^{1.} All performance data measured at 10 W, 25 °C, beginning of Life (BOL). 2. Weighted average "center of mass" spectral point at 25 °C at $P_{\rm O}$ 3. Change in $\Delta\lambda$ mean with case temperature over $T_{\rm op}$

Fiber Laser Feedback Isolation Specification

Wavelength Range (nm)	Isolation (dB)	Reflectivity (%)	
1060–1100	> 30	> 99.9%	
1050–1150	> 25	> 99.7%	

Absolute Maximum Ratings

Parameter	Symbol	Minimum	Typical	Maximum
Operating current	I_{op}	-	-	14 A
Reverse voltage	V_{rvs}	-	-	2.0 V
Case operating temperature ¹	Тор	15 °C	-	50 °C
Storage temperature ²	Tstg	-30 °C	-	70 °C
Lead soldering temperature, 10 s max	Tls	-	-	300 °C
Relative humidity, non-condensing, ambient < 45°C	RH	-	-	85%
Electrostatic discharge (ESD) ³	Vesd	-	-	500 V
Fiber bend radius (long term deployment) ⁴		30 mm	-	-
Fiber axial pull force, 15 s		-	-	5 N
Fiber side pull force, 15 s		-	-	2.5 N

^{1.} Noncondensing, maximum

Configurations

Product Code	Wavelength Range	Fiber NA
L4-9891510-100E	905 – 928 nm	0.22
L4-9891510-100F	905 – 928 nm	0.15
L4-9894010-100E	928 – 950 nm	0.22
L4-9894010-100F	928 – 950 nm	0.15
L4-9897510-100E	963 – 985 nm	0.22
L4-9897510-100F	963 – 985 nm	0.15

Ordering Information

For more information on this or other products and their availability, please contact your local JDSU account manager or JDSU directly at 1-800-498-JDSU (5378) in North America and +800-5378-JDSU worldwide or via e-mail at customer.service@jdsu.com.

Sample: L4-9891510-100E

^{2.} Noncondensing, 2000 hours

^{3.~}C=100 pF, R=1.5 k Ω , human body model, shown to be not damaging to its LI characteristics or its reliability, I-V curves may change in this ESD environment

^{4.} Minimum bend radius of 30 mm is for long term mechanical fiber reliability; however for 0.15 NA some optical loss may occur and a minimum bend radius of 45 mm is recommended for layout with multiple fiber coils.



User Safety	

Safety and Operating Considerations

The laser light emitted from this diode laser is invisible and may be harmful to the human eye. Avoid looking directly into the diode laser or into the collimated beam along its optical axis when the device is in operation.

CAUTION: THE USE OF OPTICAL INSTRUMENTS WITH THIS PRODUCT WILL INCREASE EYE HAZARD.

Operating the diode laser outside of its maximum ratings may cause device failure or a safety hazard. Power supplies used with the component must be employed such that the maximum peak optical power cannot be exceeded. CW diode lasers may be damaged by excessive drive current or switching transients. When power supplies are used, the diode laser should be connected with the main power on and the output voltage at zero. The current should be increased slowly while the diode laser output power and the drive current are monitored.

Device degradation accelerates with increased temperature, and therefore careful attention to minimizing the case temperature is advised. For example, life expectancy will decrease by a factor of four if the case is operated at 50 °C rather than 25 °C.

A proper heatsink for the diode laser on a thermal radiator will greatly enhance laser life. Firmly mount the laser on a radiator with a thermal impedance of less than 0.5 °C/W for increased reliability.

ESD PROTECTION—Electrostatic discharge is the primary cause of unexpected diode laser failure. Take extreme precaution to prevent ESD. Use wrist straps, grounded work surfaces, and rigorous antistatic techniques when handling diode lasers.

Labeling

21 CFR 1040.10 Compliance

Because of the small size of these devices, each of the labels shown is attached to the individual shipping container. They are illustrated here to comply with 21 CFR 1040.10 as applicable under the Radiation Control for Health and Safety Act of 1968.

Serial Number Identification Label



Output Power Danger Label

